

2N6766 Information

Heisener.com

Part Number 2N6766

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 200V TO-204AE TO-3

Package TO-204AE

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com

Request a Quote



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N6766 Specifications

Manufacturer Part Number	2N6766
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-204AE
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	115nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	4W (Ta), 150W (Tc)
Rds On (Max) @ Id, Vgs	90 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-3
Package / Case	TO-204AE
	Report errors?

2N6766 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N6766 Payment Methods



















2N6766 Shipping Methods













If you have any question about 2N6766, please do not hesitate to contact us!

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